

CDx4AC373、CDx4ACT373 八路透明三态锁存器

1 特性

- 防 SCR 闩锁 CMOS 工艺和电路设计
- 双极 FAST*/AS/S 的速度，同时功耗显著降低
- 平衡传播延迟
- 交流类型的工作电压范围为 1.5V 至 5.5V，并在电源电压的 30% 时具有平衡的抗噪性能
- $\pm 24\text{mA}$ 输出驱动电流
 - 扇出到 15 个 FAST* IC
 - 驱动 $50\ \Omega$ 传输线路

2 说明

RCA-CDx4AC373 和 CDx4ACT373 八路透明三态锁存器使用 RCA 高级 CMOS 技术。

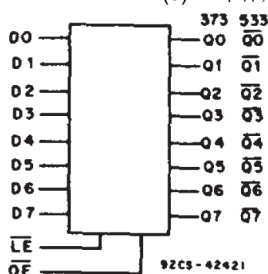
器件信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾	本体尺寸 ⁽³⁾
CDx4AC/ACT373	DW (SOIC , 20)	12.80mm × 10.3mm	12.80mm × 7.50mm
	N (PDIP , 20)	24.33mm × 9.4mm	24.33mm × 6.35mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。

(3) 本体尺寸 (长 × 宽) 为标称值，不包括引脚。



逻辑图 (正逻辑)

*FAST 是 Fairchild Semiconductor Corp. 的注册商标。



本资源的原文使用英文撰写。为方便起见，TI 提供了译文；由于翻译过程中可能使用了自动化工具，TI 不保证译文的准确性。为确认准确性，请务必访问 ti.com 参考最新的英文版本 (控制文档)。

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3 Pin Configuration and Functions

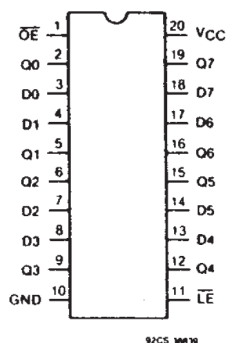


图 3-1. CDx4AC373, CDx4ACT373

PIN		I/O	DESCRIPTION
NAME	NO.		
OE	1	Input	3-state output enable input
0Q	2	Output	Output for channel 0
0D	3	Input	Input for channel 0
1D	4	Input	Input for channel 1
1Q	5	Output	Output for channel 1
2Q	6	Output	Output for channel 2
2D	7	Input	Input for channel 2
3D	8	Input	Input for channel 3
3Q	9	Output	Output for channel 3
GND	10	—	Ground
LE	11	Input	Latch enable input (active HIGH)
4Q	12	Output	Output for channel 4
4D	13	Input	Input for channel 4
5D	14	Input	Input for channel 5
5Q	15	Output	Output for channel 5
6Q	16	Output	Output for channel 6
6D	17	Input	Input for channel 6
7D	18	Input	Input for channel 7
7Q	19	Output	Output for channel 7
V _{CC}	20	—	Supply voltage

4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply-voltage	-0.5	6	V
I _{IK}	Input diode current	(V _I < -0.5 V or V _I > V _{CC} + 0.5 V)	±20	mA
I _{OK}	Output diode current	(V _O < -0.5 V or V _O > V _{CC} + 0.5 V)	±50	mA
I _O	Output source or sink current per output pin	(V _O > -0.5 V or V _O < V _{CC} + 0.5 V)	±50	mA
	V _{CC} or ground current, I _{CC} or I _{GND}		±100	mA ⁽²⁾
T _{stg}	Storage temperature	-65	+150	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) For up to 4 outputs per device; add ± 25 mA for each additional output.

4.2 ESD Ratings

		Value	UNIT
V _(ESD)	Electrostatic discharge Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

4.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	CHARACTERISTIC	MIN	MAX	UNIT
V _{CC} ⁽²⁾	Supply-voltage			
	AC types	1.5	5.5	V
	ACT types	4.5	5.5	
V _I , V _O	Input or output voltage	0	V _{CC}	V
dt/dv	Input rise and fall slew rate			
	at 1.5 V to 3 V (AC types)	0	50	ns/V
	at 3.6 V to 5.5 V (AC types)	0	20	ns/V
	at 4.5 V to 5.5 V (ACT types)	0	10	ns/V
T _A	Operating-temperature range	-55	+125	°C

- (1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report: Implications of Slow or Floating CMOS Inputs.
- (2) Unless otherwise specified, all voltages are referenced to ground.

4.4 Thermal Information

THERMAL METRIC ⁽¹⁾		CDx4AC/ACT373		UNIT
		N (PDIP)	DW (SOIC)	
		20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	50	101.2	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report ([SPRA953](#)).

4.5 Electrical Characteristics: AC Series

CHARACTERISTICS		TEST CONDITIONS		V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C						UNIT
					+25		-40 to+85		-55 to +125		
		V _I (V)	I _O (mA)		MIN	MAX	MIN	MAX	MIN	MAX	
V _{IH}	High-Level Input Voltage			1.5	1.2	—	1.2	—	1.2	—	V
				3	2.1	—	2.1	—	2.1	—	
				5.5	3.85	—	3.85	—	3.85	—	
V _{IL}	Low-Level Input Voltage			1.5	—	0.3	—	0.3	—	0.3	V
				3	—	0.9	—	0.9	—	0.9	
				5.5	—	1.65	—	1.65	—	1.65	
V _{OH}	High-Level Output Voltage	V _{IH} or V _{IL}	-0.05	1.5	1.4	—	1.4	—	1.4	—	V
			-0.05	3	2.9	—	2.9	—	2.9	—	
			-0.05	4.5	4.4	—	4.4	—	4.4	—	
			-4	3	2.58	—	2.48	—	2.4	—	
			-24	4.5	3.94	—	3.8	—	3.7	—	
		(1), (2)	-75	5.5	—	—	3.85	—	—	—	
			-50	5.5	—	—	—	—	3.85	—	
V _{IH} or V _{IL}	Low-Level Output Voltage	V _{IH} or V _{IL}	0.05	1.5	—	0.1	—	0.1	—	0.1	V
			0.05	3	—	0.1	—	0.1	—	0.1	
			0.05	4.5	—	0.1	—	0.1	—	0.1	
			12	3	—	0.36	—	0.44	—	0.5	
			24	4.5	—	0.36	—	0.44	—	0.5	
		(1), (2)	75	5.5	—	—	—	1.65	—	—	
			50	5.5	—	—	—	—	—	1.65	
I _I	Input Leakage Current	V _{CC} or GND		5.5	—	±0.1	—	±1	—	±1	μA
I _{OZ}	3-State Leakage Current	V _{IH} or V _{IL} V _O = V _{CC} or GND		5.5	—	±0.5	—	±5	—	±10	μA
I _{CC}	Quiescent Supply Current, MSI	V _{CC} or GND	0	5.5	—	8	—	80	—	160	μA

(1) Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

(2) Test verifies a minimum 50-ohm transmission-line-drive capability at +85° C, 75 ohms at +125°C.

4.6 Electrical Characteristics: ACT Series

CHARACTERISTICS		TEST CONDITIONS		V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C						UNIT
					+25		-40 to+85		-55 to +125		
		V _I (V)	I _O (mA)		MIN	MAX	MIN	MAX	MIN	MAX	
V _{IH}	High-level input voltage			4.5 to 5.5	2	—	2	—	2	—	V
V _{IL}	Low-level input voltage			4.5 to 5.5	—	0.8	—	0.8	—	0.8	V
V _{OH}	High-level output voltage	V _{IH} or V _{IL}	-0.05	4.5	4.4	—	4.4	—	4.4	—	V
			-24	4.5	3.94	—	3.8	—	3.7	—	
		(1), (2)	-75	5.5	—	—	3.85	—	—	—	
		-50	5.5	—	—	—	—	3.85	—		

CHARACTERISTICS		TEST CONDITIONS		V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C						UNIT
					+25		-40 to+85		-55 to +125		
		V _I (V)	I _O (mA)		MIN	MAX	MIN	MAX	MIN	MAX	
V _{OH}	Low-level output voltage	V _{IH} or V _{IL}	0.05	4.5	—	0.1	—	0.1	—	0.1	V
			24	4.5	—	0.36	—	0.44	—	0.5	
		(1), (2)	75	5.5	—	—	—	1.65	—	—	
			50	5.5	—	—	—	—	—	1.65	
V _{OH}	Input leakage current	V _{CC} or GND		5.5	—	±0.1	—	±1	—	±1	
I _{OZ}	3-state leakage current	V _{IH} or V _{IL} V _O = V _{CC} or GND		5.5	—	±0.5	—	±5	—	±10	μ A
I _{CC}	Quiescent supply current, msi	V _{CC} or GND	0	5.5	—	8	—	80	—	160	μ A
	Additional quiescent supply current per input pin	V _{CC} -2.1		4.5 to 5.5	—	2.4	—	28	—	3	mA
Δ I _{CC}	TTL inputs high										
	1 unit load										

(1) Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

(2) Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C. 75 ohms at +125°C.

表 4-1. Act Input Loading Table

INPUT	UNIT LOAD ⁽¹⁾	
	ACT373	ACT533
$\overline{OE}$	0.87	0.87
Dn	0.5	0.5
$\overline{LE}$	0.8	0.8

(1) Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g. 2.4 mA max. @ 25°C.

4.7 Prerequisite for Switching: AC Series

SYMBOL	CHARACTERISTICS	V _{CC} (V)	AMBIENT TEMPERATURE (T _A) -°C				UNIT
			-40 to +85		-55 to +125		
			MIN	MAX	MIN	MAX	
t _W	LE Pulse Width	1.5	44	—	50	—	ns
		3.3 ⁽¹⁾	4.9	—	5.6	—	
		5 ⁽²⁾	3.5	—	4	—	
t _{su}	Setup Time Data to LE	1.5	2	—	2	—	ns
		3.3	2	—	2	—	
		5	2	—	2	—	
t _H	Hold Time Data to LE	1.5	33	—	38	—	ns
		3.3	3.7	—	4.2	—	
		5	2.6	—	3	—	

(1) 3.3 V: min. is @ 3 V

(2) 5 V: min. is @ 4.5 V

4.8 Switching Characteristics: AC Series

$t_r, t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$

SYMBOL	CHARACTERISTICS	V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C				UNIT
			-40 to +85		-55 to +125		
			MIN	MAX	MIN	MAX	
t _{PLH}	Propagation Delays: Data to Qn 373	1.5	—	96	—	106	ns
		3.3 ⁽¹⁾	3.1	10.8	3	11.9	
		5 ⁽²⁾	2.2	7.7	2.1	8.5	
t _{PHL}	533	1.5	—	119	—	131	ns
t _{PLH}		3.3	3.8	13.4	3.7	14.7	
t _{PHL}		5	2.7	9.5	2.6	10.5	
t _{PLH}	LE on Qn 373	1.5	—	136	—	150	ns
t _{PHL}		3.3	4.3	15.2	4.2	16.8	
t _{PLH}		5	3.1	10.9	3	12	
t _{PHL}	533	1.5	—	136	—	150	ns
t _{PLH}		3.3	4.3	15.3	4.2	16.8	
t _{PHL}		5	3.1	10.9	3	12	
t _{PZL}	Output Enable Times	1.5	—	119	—	131	ns
t _{PZH}		3.3	4.1	14.4	4	15.8	
t _{PLZ}		5	2.7	9.5	2.6	10.5	
t _{PLZ}	Output Disable Times	1.5	—	131	—	144	ns
t _{PHZ}		3.3	3.7	13.1	3.6	14.4	
C _{PD} ⁽³⁾		5	3	10.5	2.9	11.5	
C _{PD} ⁽³⁾	Power Dissipation Capacitance	—	63 Typ.		63 Typ.		pF
V _{OHV}	Min. (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	5	4 Typ. @ 25° C				V
V _{OLP}	Max. (Peak) V _{OL} During Switching of Other Outputs (Output Under Test Not Switching)	5	1 Typ. @25° C				V
C _I	Input Capacitance	—	—	10	—	10	pF
C _O	3-State Output Capacitance	—	—	15	—	15	pF

(1) 3.3 V: min. is @ 3.6 V

(2) 5 V: min. is @ 5.5 V

(3) C_{PD} is used to determine the dynamic power consumption, per latch.

4.9 Prerequisite for Switching: ACT Series

SYMBOL	CHARACTERISTICS	V _{CC} (V)	AMBIENT TEMPERATURE (T _A) -°C				UNIT
			-40 to +85		-55 to +125		
			MIN	MAX	MIN	MAX	
t _W	LE Pulse Width	5 ⁽¹⁾	3.6	—	4	—	ns
t _{SU}	Setup Time Data to LE	5	2	—	2	—	ns
t _H	Hold Time Data to LE	5	2.7	—	3	—	ns

(1) 5 V: min. is @ 4.5 V

4.10 Switching Characteristics: ACT Series

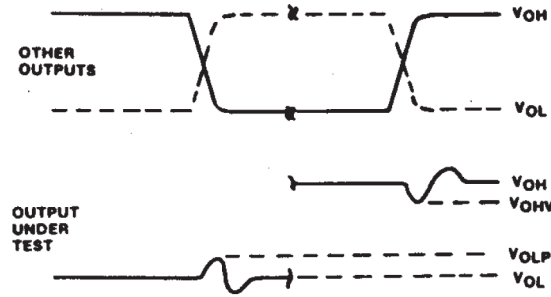
$t_r, t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$

SYMBOL	CHARACTERISTICS	V _{CC} (V)	AMBIENT TEMPERATURE (T _A) -°C				UNIT
			-40 to +85		-55 to +125		
			MIN	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation Delays: Data to Qn 373	5 ⁽¹⁾	2.7	9.5	2.6	10.4	ns
	533		3	10.4	2.9	11.4	
t _{PLH} t _{PHL}	$\overline{L} \overline{E}$ to Qn 373 533	5	3.1	11.4	3	12.5	ns
t _{PZL} t _{PZH}	Output Enable Times	5	3.5	12.3	3.4	13.5	ns
t _{PLZ} t _{PHZ}	Output Disable Times	5	3.2	11.4	3.1	12.5	ns
C _{PD} ⁽²⁾	Power Dissipation Capacitance	—	63 Typ.		63 Typ.		pF
V _{OHV}	Min. (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	5	4 Typ. @ 25° C				V
V _{OLP}	Max. (Peak) V _{OL} During Switching of Other Outputs (Output Under Test Not Switching)	5	1 Typ. @25° C				V
C _I	Input Capacitance	—	— 10		— 10		pF
C _O	3-State Output Capacitance	—	— 15		— 15		pF

(1) 5 V: min. is @ 5.5 V

(2) C_{PD} is used to determine the dynamic power consumption, per latch.

5 Parameter Measurement Information



- V_{OHV} AND V_{OLP} ARE MEASURED WITH RESPECT TO A GROUND REFERENCE NEAR THE OUTPUT UNDER TEST.
- INPUT PULSES HAVE THE FOLLOWING CHARACTERISTICS: $PRR \leq 1$ MHz, $t_r = 3$ ns, $t_f = 3$ ns, SKEW 1 ns.
- R.F. FIXTURE WITH 700-MHz DESIGN RULES REQUIRED. IC SHOULD BE SOLDERED INTO TEST BOARD AND BYPASSED WITH $0.1 \mu F$ CAPACITOR. SCOPE AND PROBES REQUIRE 700-MHz BANDWIDTH.
- 92CS-42406

图 5-1. Simultaneous Switching Transient Waveforms.

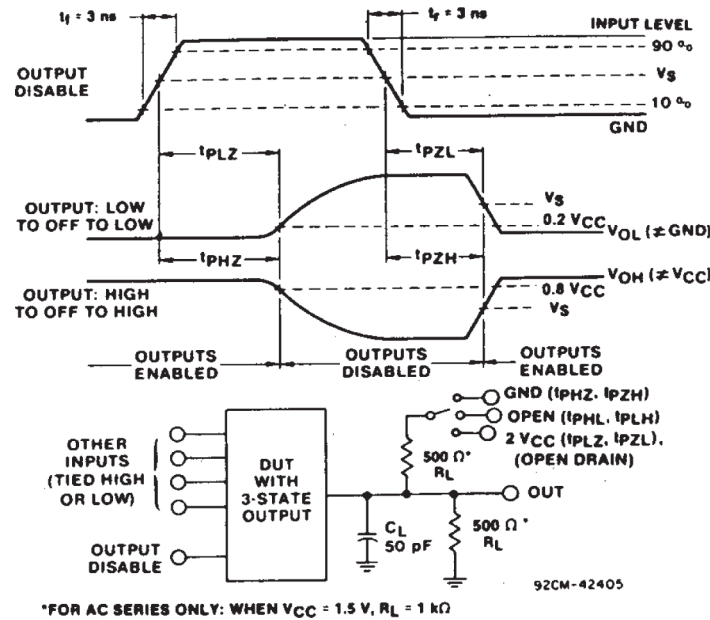


图 5-2. Three-state Propagation Delay Waveforms and Test Circuit.

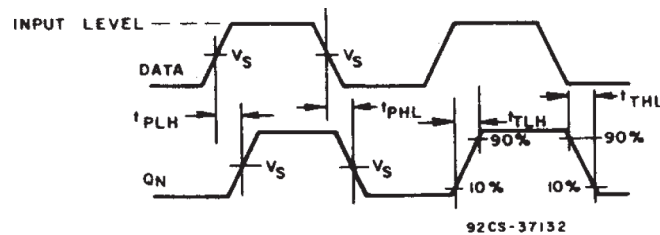


图 5-3. Data to Qn Output Propagation Delays and Output Transition Times.

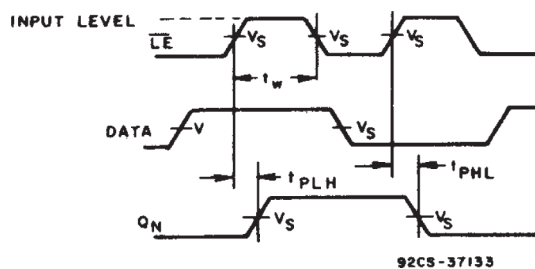


图 5-4. Latch Enable Propagation Delays.

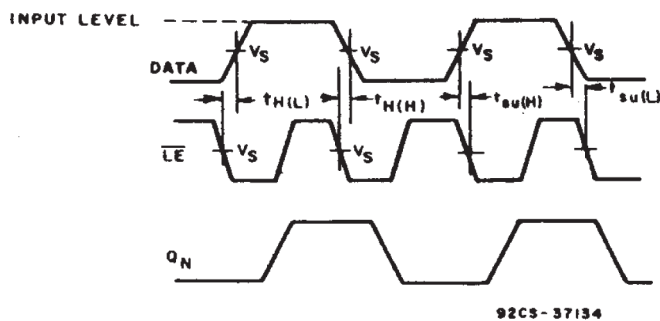


图 5-5. Latch Enable Prerequisite Times.

	CD54/74AC	CD54/74ACT
Input Level	V_{CC}	3 V
Input Switching Voltage, V_S	$0.5 V_{CC}$	1.5 V
Output Switching Voltage, V_S	$0.5 V_{CC}$	$0.5 V_{CC}$

6 Detailed Description

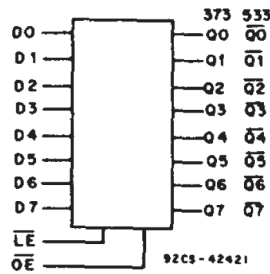
6.1 Overview

The RCA-CD54/74AC373 and the CD54/74ACT373 octal transparent 3-state latches use the RCA ADVANCED CMOS technology. The outputs are transparent to the inputs when the Latch Enable ($\overline{LE}$) is HIGH. When the Latch Enable ($\overline{LE}$) goes LOW, the data is latched. The Output Enable ($\overline{OE}$) controls the 3-state outputs. When the Output Enable ($\overline{OE}$) is HIGH, the outputs are in the high-impedance state. The latch operation is independent of the state of the Output Enable.

The CD74AC/ACT373 are supplied in 20-lead dual-in-line plastic packages (E suffix) and in 20-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC/ACT373, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

6.2 Functional Block Diagram



6.3 Functional Block Diagram

表 6-1. Truth Table

Output Enable	Latch Enable	Data	AC/ACT373 Output
L	H	H	H
L	H	L	L
L	L	l	L
L	L	h	H
H	X	X	Z

7 Application and Implementation

7.1 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the [Recommended Operating Conditions](#) table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μf is recommended; if there are multiple VCC pins, then 0.01 μf or 0.022 μf is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μf and a 1 μf are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

7.2 Layout Guidelines

7.2.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only three of the four buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient. Floating outputs is generally acceptable, unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the I.O's so they also cannot float when disabled.

8 Device and Documentation Support

8.1 Documentation Support (Analog)

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
CD54AC373	Click here	Click here	Click here	Click here	Click here
CD74AC373	Click here	Click here	Click here	Click here	Click here
CD54ACT373	Click here	Click here	Click here	Click here	Click here
CD74ACT373	Click here	Click here	Click here	Click here	Click here

8.2 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com](#) 上的器件产品文件夹。点击 [通知](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

8.3 支持资源

[TI E2E™ 中文支持论坛](#) 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [使用条款](#)。

8.4 Trademarks

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8.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

8.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

9 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision * (April 2002) to Revision A (May 2024)	Page
• 添加了 器件信息表 、 引脚功能表 、 ESD 等级表 、 热性能信息表 、 器件功能模式 、 应用和实施部分 、 器件和文档支持部分 以及 机械、封装和可订购信息部分	1
• Updated R _{θJA} values: DW = 40 to 101.2, all values in °C/W	5

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CD54AC373F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54AC373F3A
CD54AC373F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54AC373F3A
CD54ACT373F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54ACT373F3A
CD54ACT373F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54ACT373F3A
CD74AC373E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74AC373E
CD74AC373E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74AC373E
CD74AC373M	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-55 to 125	AC373M
CD74AC373M96	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC373M
CD74AC373M96.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC373M
CD74ACT373E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74ACT373E
CD74ACT373E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74ACT373E
CD74ACT373M	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-55 to 125	ACT373M
CD74ACT373M96	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT373M
CD74ACT373M96.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT373M

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54AC373, CD54ACT373, CD74AC373, CD74ACT373 :

- Catalog : [CD74AC373](#), [CD74ACT373](#)
- Military : [CD54AC373](#), [CD54ACT373](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC373M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74AC373M96	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
CD74ACT373M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74AC373M96	SOIC	DW	20	2000	356.0	356.0	45.0
CD74AC373M96	SOIC	DW	20	2000	356.0	356.0	45.0
CD74ACT373M96	SOIC	DW	20	2000	356.0	356.0	45.0

TUBE



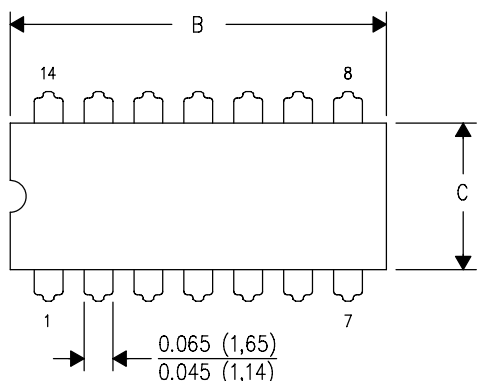
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
CD74AC373E	N	PDIP	20	20	506	13.97	11230	4.32
CD74AC373E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74ACT373E	N	PDIP	20	20	506	13.97	11230	4.32
CD74ACT373E.A	N	PDIP	20	20	506	13.97	11230	4.32

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS **	14	16	18	20
DIM				
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - The 20 pin end lead shoulder width is a vendor option, either half or full width.



4220724/A 05/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

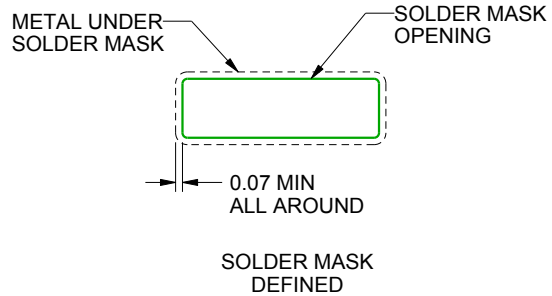
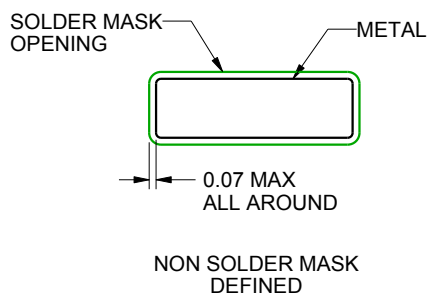
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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